1.	Record Nr. Autore Titolo	UNINA9910876725803321 Kitai Adrian Principles of Solar Cells, LEDs and Diodes : The role of the PN junction
	Pubbl/distr/stampa	Hoboken, : Wiley, 2011
	ISBN	1-283-20444-4 9786613204448 1-119-97454-2 1-119-97455-0
	Descrizione fisica	1 online resource (334 p.)
	Classificazione	TEC021000 ZN 4800
	Disciplina	621.3815/2 621.38152
	Soggetti	Diodes, Semiconductor Light emitting diodes Semiconductors Junctions Solar cells Diodes, Semiconductor - Junctions Semiconductors Electrical & Computer Engineering Engineering & Applied Sciences Electrical Engineering
	Lingua di pubblicazione	Inglese
	Formato	Materiale a stampa
	Livello bibliografico	Monografia
	Note generali	Description based upon print version of record.
	Nota di contenuto	Principles of Solar Cells,LEDs and Diodes; Contents; Introduction; Acknowledgements; 1 Semiconductor Physics; 1.1 Introduction; 1.2 The Band Theory of Solids; 1.3 The Kronig-Penney Model; 1.4 The Bragg Model; 1.5 Effective Mass; 1.6 Number of States in a Band; 1.7 Band Filling; 1.8 Fermi Energy and Holes; 1.9 Carrier Concentration; 1.10 Semiconductor Materials; 1.11 Semiconductor Band Diagrams; 1.12 Direct Gap and Indirect Gap Semiconductors; 1.13 Extrinsic Semiconductors; 1.14 Carrier Transport in Semiconductors; 1.15 Equilibrium and Non-Equilibrium Dynamics

Emission and Absorption; 3.1 Introduction to Luminescence and Absorption; 3.2 Physics of Light Emission; 3.3 Simple Harmonic Radiator; 3.4 Quantum Description; 3.5 The Exciton; 3.6 Two-Electron Atoms; 3.7 Molecular Excitons; 3.8 Band-to-Band Transitions; 3.9 Photometric Units; 3.10 Summary; Suggestions for Further Reading; Problems; 4 The Solar Cell; 4.1 Introduction; 4.2 Light Absorption; 4.3 Solar Radiation; 4.4 Solar Cell Design and Analysis; 4.5 Thin Solar Cells 4.6 Solar Cell Generation as a Function of Depth 4.7 Solar Cell Efficiency4.8 Silicon Solar Cell Technology: Wafer Preparation; 4.9 Silicon Solar Cell Technology: Solar Cell Finishing; 4.10 Silicon Solar Cells: Amorphous Silicon; 4.12 Telluride/Selenide/Sulphide Thin-Film Solar Cells; 4.13 High-Efficiency Multijunction Solar Cells; 4.14 Concentrating Solar Systems; 4.15 Summary; Suggestions for Further Reading; Problems; 5 Light Emitting Diodes; 5.1 Introduction; 5.2 LED Operation and Device Structures; 5.3 Emission Spectrum; 5.4 Non-Radiative Recombination 5.5 Optical Outcoupling5.6 GaAs LEDs; 5.7 GaAs1-xPx LEDs; 5.8 Double Heterojunction AlxGa1-xAs LEDs; 5.9 AlGaInP LEDs; 5.10 Ga1- xInxN LEDs; 5.11 LED Structures for Enhanced Outcoupling and Power Output; 5.12 Summary; Suggestions for Further Reading; Problems; 6 Organic Semiconductors, OLEDs and Solar Cells; 6.1 Introduction to Organic Electronics; 6.2 Conjugated Systems; 6.3 Polymer OLEDs; 6.4 Small-Molecule OLEDs; 6.5 Anode Materials; 6.6 Cathode Materials; 6.7 Hole Injection Layer; 6.8 Electron Injection Layer; 6.9 Hole Transport Layer; 6.10 Electron Transport Layer 6.11 Light Emitting Material Processes
Sommario/riassunto The book will cover the two most important applications of semiconductor diodes - solar cells and LEDs - together with quantitative coverage of the physics of the PN junction at the senior undergraduate level. It will include: Review of semiconductor physicsIntroduction to PN diodesThe solar cellPhysics of efficient conversion of sunlight into electrical energySemiconductor solar cell materials and device physicsAdvanced solar cell materials and devicesThe light emitting diodePhysics of efficient conversion of electrical energy into lightSemiconductor li